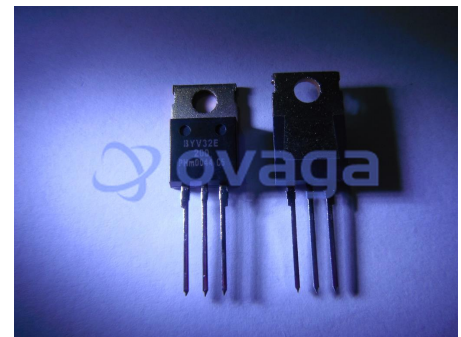


Fast / Ultrafast Diode, 200 V, 10 A, Dual Common Cathode, 1.15 V, 25 ns, 125 A

Manufacturers	NXP Semiconductor
Package/Case	TO-220
Product Type	Transistors
RoHS	
Lifecycle	



Images are for reference only

Please submit RFQ for BYV32E-200 or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

BYV32E-200 is a high-voltage rectifier diode that can handle a maximum voltage of 200V and a maximum current of 20A. It has a fast switching speed and low reverse recovery time, which makes it suitable for use in high-frequency applications.

Features

High voltage capability: 200V

High current capability: 20A

Fast switching speed

Low reverse recovery time

Low forward voltage drop

Application

Switch-mode power supplies

High-frequency rectification

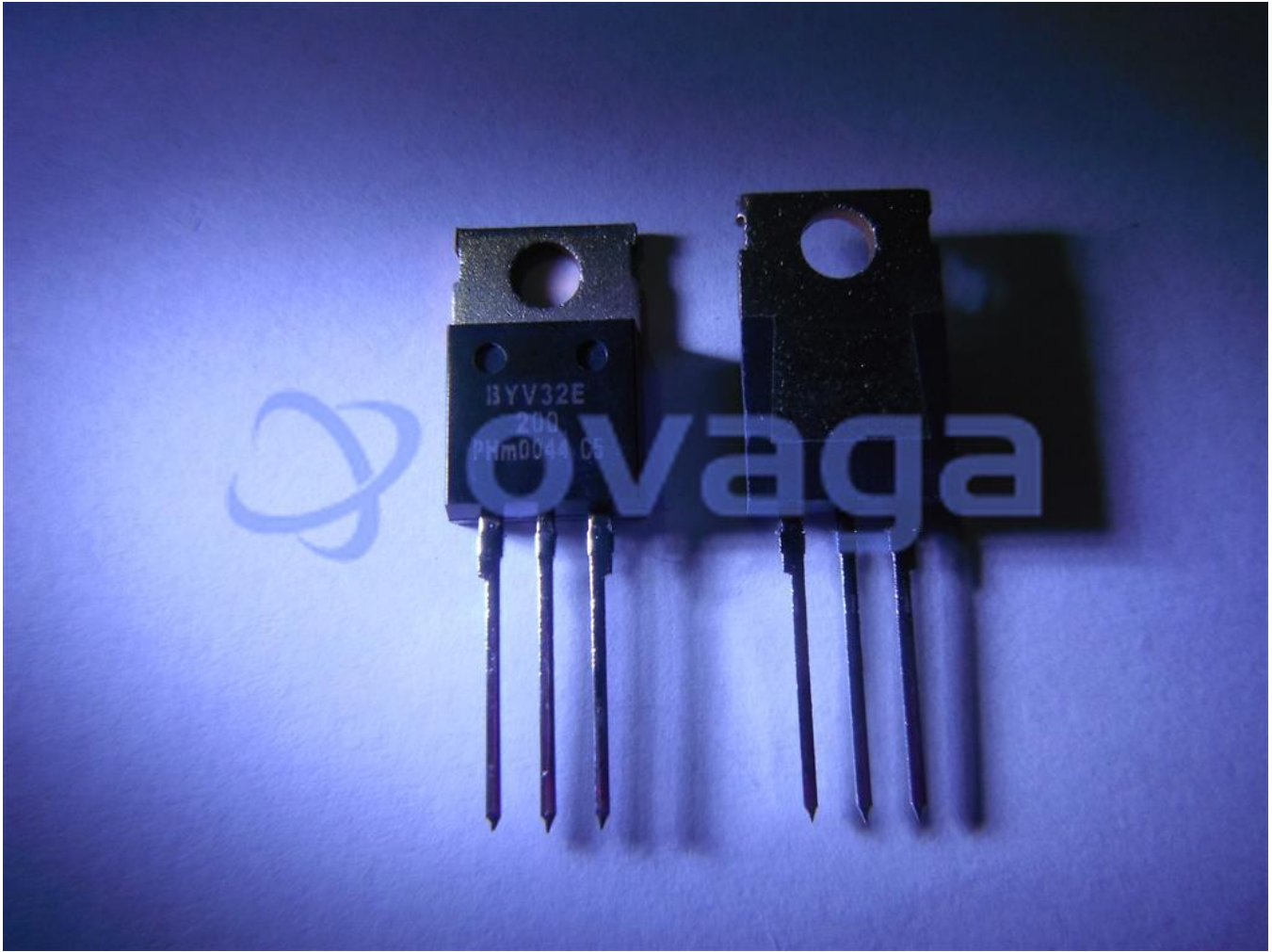
Free-wheeling diodes

Snubber diodes

Reverse battery protection

Flyback diodes in DC-DC converters

Output rectifiers in high-frequency inverters





Related Products



[2N7002PS](#)

NXP Semiconductor
SOT-363



[PSMN1R0-30YLD](#)

NXP Semiconductor
LFPAK56



[PBSS4350Z](#)

NXP Semiconductor
SOT-223



[PBSS5350Z](#)

NXP Semiconductor
SOT223



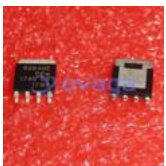
[74LYC1G18GW](#)

NXP Semiconductor
SOT363



[PSMN1R0-40YLD](#)

NXP Semiconductor
N-channel



[BUK9Y29-40E](#)

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[BSN20](#)

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SOT23